

# Ultralow, I<sub>Q</sub>, anyCAP<sup>®</sup> Low Dropout Regulator

**ADP3342** 

#### **FEATURES**

Accuracy over Line and Load:  $\pm 4.0\%$  @ 25°C,  $\pm 5\%$  over Temperature
Ultralow Dropout Voltage: 300 mV (Typ) @ 300 mA
Requires Only  $C_0 = 1.0~\mu F$  for Stability
anyCAP = Stable with any Type of Capacitor
(Including MLCC)
Current and Thermal Limiting
Low Shutdown Current:  $< 2~\mu A$ 1.7  $V \le V_{IN} \le 6~V$ 2.8  $V \le VCC \le 6~V$   $V_{OUT} = 1.2~V~\pm 5\%$ 

-40°C to +100°C Ambient Temperature Range

**Ultrasmall Thermally Enhanced 8-Lead MSOP Package** 

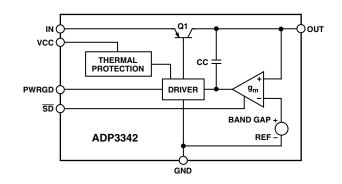
APPLICATIONS Notebook PCs Desktop PCs

#### **GENERAL DESCRIPTION**

The ADP3342 is a unique member of the ADP330x family of precision low dropout anyCAP voltage regulators. The ADP3342 operates with an input voltage range of 1.7 V to 6 V and delivers a continuous load current up to 300 mA. In order to support the ability to regulate from such a low input voltage, the power rail to the IC, VCC, has been split off from the main power rail,  $V_{\rm IN}$ , from which the output is powered.

The ADP3342 stands out from the conventional LDOs with the lowest thermal resistance of any MSOP-8 package and an enhanced process that enables it to offer performance advantages beyond its competition. Its patented design requires only a 1.0  $\mu F$  output capacitor for stability. This device is insensitive to output capacitor Equivalent Series Resistance (ESR) and is stable with any good quality capacitor, including ceramic (MLCC) types for space-restricted applications. The dropout voltage of the ADP3342 is only 190 mV (typical) at 300 mA. This device also includes a safety current limit, thermal overload protection, and a shutdown control pin.

#### FUNCTIONAL BLOCK DIAGRAM



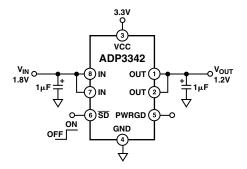


Figure 1. Typical Application Circuit

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# $\textbf{ADP3342-SPECIFICATIONS}^{1 \text{ (VCC} = 3.0 \text{ V, V}_{\text{IN}} = 1.8 \text{ V, C}_{\text{IN}} = \text{C}_{\text{OUT}} = 1 \text{ } \mu\text{F, T}_{\text{A}} = 0^{\circ}\text{C to } + 100^{\circ}\text{C and T}_{\text{A}} = -40^{\circ}\text{C to } + 100^{\circ}\text{C$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
OUTPUT						
Voltage Accuracy	V <sub>OUT</sub>	VCC = 2.8 V to 6 V, $V_{IN}$ = 1.7 V to 6 V $I_L$ = 0.1 mA to 300 mA $T_A$ = 25°C	-4.0		+4.0	%
		$VCC = 2.8 \text{ V to 6 V}, V_{IN} = 1.7 \text{ V to 6 V}$ $I_L = 0.1 \text{ mA to } 300 \text{ mA}$	-5.0		+5.0	%
Line Regulation		$T_A = -40^{\circ}\text{C to } +100^{\circ}\text{C}$ $VCC = 2.8 \text{ V to 6 V}, V_{IN} = 1.7 \text{ V to 6 V}$ $T_A = 25^{\circ}\text{C}$		0.04		mV/V
Load Regulation		$I_L = 0.1 \text{ mA to } 300 \text{ mA}$ $T_A = 25^{\circ}\text{C}$		0.12		mV/mA
Dropout Voltage	$V_{DROP}$	$V_{OUT} = 98\%$ of $V_{OUTNOM}$		100	450	
		$I_L = 300 \text{ mA}$		190 125	450	mV mV
		$I_{L} = 200 \text{ mA}$ $I_{L} = 100 \text{ mA}$		70		mV
Current Limiting	I <sub>LIM</sub>	$VCC = 3 \text{ V}, V_{IN} = 1.8 \text{ V}$		450		mA
Output Noise	V <sub>NOISE</sub>	$f = 10 \text{ Hz}-100 \text{ kHz}, C_L = 1 \mu\text{F}$		60		μV rms
		I <sub>L</sub> = 300 mA				
OPERATING CURRENTS	_	1 000 A T 4000 11000		2.0	0.5	
Ground Current in Regulation	$I_{GND}$	$I_L = 300 \text{ mA}, T_A = -40^{\circ}\text{C to } +100^{\circ}\text{C}$		3.0	8.5	mA
		$I_L = 300 \text{ mA}, T_A = 0^{\circ}\text{C to } 100^{\circ}\text{C}$		3.0	6.0	mA
		$I_L = 300 \text{ mA}, T_A = 25^{\circ}\text{C}$ $I_L = 200 \text{ mA}$		3.0 2.0	4.0	mA mA
		$I_{L} = 200 \text{ mA}$ $I_{L} = 0.1 \text{ mA}$		100	175	μΑ
VCC Current in Regulation	IVCC	$I_{L} = 300 \text{ mA}$		100	170	μΑ
Ground Current in Shutdown	I <sub>GNDSD</sub>	$SD = 0 \text{ V}, \text{ VCC} = 6 \text{ V}, \text{ V}_{\text{IN}} = 1.8 \text{ V}$		0.01	2	μΑ
SHUTDOWN						
Threshold Voltage	$V_{THSD}$	ON	VCC -	0.9		V
		OFF			0.6	V
SD Input Current	$I_{SD}$	$0 \le SD \le 6 \text{ V}$		1.4	7	μA
Output Current in Shutdown	$I_{OSD}$	$T_A = 25^{\circ}C$ , $VCC = 6 V$ , $V_{IN} = 6 V$		0.01	1	μA
		$T_A = 100$ °C, VCC = 6 V, $V_{IN} = 6$ V		0.01	2	μA
PWRGD	_	W 10W W00 10W	0.05			
Power Good Output Voltage	I <sub>PWRGDL</sub> V <sub>PWRGDL</sub> <sup>2</sup>	$V_{PWRGD} = 1.2 \text{ V}, \text{ VCC} = 3.0 \text{ V}$	0.85	1.5	0.4	mA
	VPWRGDL	$I_{PWRGD} = 300 \mu\text{A}$	VICC	0.4	0.4	V
Parron Cood On Time Dalan	$\begin{array}{ c c }\hline V_{PWRGDH}^2 \\ TD1^3 \end{array}$	$I_{PWRGD} = 300 \mu\text{A}$	VCC -	0.4	300	
Power Good On-Time Delay	IDI	$I_L = 3 \text{ mA to } 300 \text{ mA},$ $C_{OUT} = 1 \mu\text{F to } 10 \mu\text{F}$	'		500	μs
	$TD2^4$	$I_L = 3 \text{ mA to } 300 \text{ mA},$	50		300	μs
		$C_{OUT} = 1 \mu F \text{ to } 10 \mu F$			500	
Power Good Off-Time Delay	TD3 <sup>5</sup>	$I_L = 3 \text{ mA to } 300 \text{ mA},$ $C_{OUT} = 1 \mu\text{F to } 10 \mu\text{F}$	0.05		1	μs
THERMAL PROTECTION						
Shutdown Temperature NOTES	TH <sub>PROT</sub>	$I_L = 100 \text{ mA}$		165		°C

Specifications subject to change without notice.

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NOTES

Ambient temperature of 100°C corresponds to a junction temperature of 125°C under typical full load test conditions.

 $<sup>^2</sup>$ V<sub>PWRGDL</sub>, V<sub>PWRGDH</sub>: Power good output voltages. Guaranteed by design and characterization.  $^3$ TD1: Delay time from V<sub>OUT</sub> crossing 1 V to PWRGD high. Guaranteed by design.  $^4$ TD2: Delay time from  $\overline{\text{SD}}$  high to PWRGD high. Guaranteed by design.

<sup>&</sup>lt;sup>5</sup>TD3: Delay time between  $\overline{SD}$  low to PWRGD low. Guaranteed by design.

#### **ABSOLUTE MAXIMUM RATINGS\***

Input Supply Voltage0.3 V to +13 V
Shutdown Input Voltage0.3 V to +13 V
Power Dissipation Internally Limited
Operating Ambient Temperature Range40°C to +100°C
Operating Junction Temperature Range40°C to +125°C
$\theta_{JA}$ (2-layer)
$\theta_{\rm IA}$ (4-layer)
$\theta_{\rm IC}$ 56°C/W
Storage Temperature Range65°C to +150°C
Lead Temperature Range (Soldering 10 sec) 300°C
Vapor Phase (60 sec)
Infrared (15 sec)
*This is a stress rating only; operation beyond these limits can cause the device
to be permanently damaged.

#### PIN CONFIGURATION



#### **ORDERING GUIDE**

Model	Output Voltage*	Package Option	Marking Code	Temperature Range
ADP3342JRM-REEL7	1.2 V	RM-8 (MSOP-8)	LJA	0°C to 100°C
ADP3342ARM-REEL7	1.2 V	RM-8 (MSOP-8)	LJB	−40°C to +100°C

<sup>\*</sup>Contact the factory for other output voltage options.

#### PIN FUNCTION DESCRIPTIONS

Pin No.	Mnemonic	Function
1, 8	NC	No Connection
2	OUT	Output of the Regulator. Bypass to ground with a 1.0 µF or larger capacitor. All pins must be connected together for proper operation.
3	VCC	Supply Voltage
4	GND	Ground Pin
5	PWRGD	Power Good. Used to indicate that output is in regulation.
6	SD	Active Low Shutdown Pin. Connect to ground to disable the regulator output. When shutdown is not used, this pin should be connected to the input pin.
7	IN	Regulator Input. All pins must be connected together for proper operation.

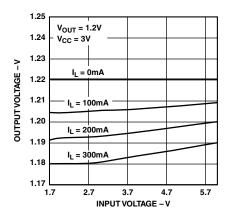
#### CAUTION\_

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the ADP3342 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

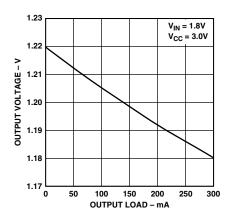


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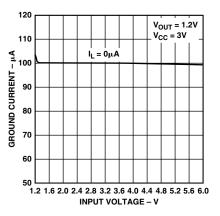
# **ADP3342—Typical Performance Characteristics**



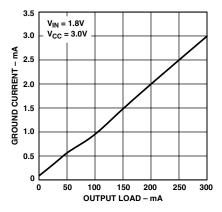
TPC 1. Line Regulation Output Voltage vs. Supply Voltage



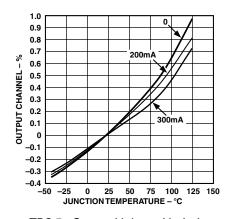
TPC 2. Output Voltage vs. Load Current



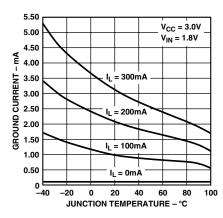
TPC 3. Ground Current vs. Supply Voltage



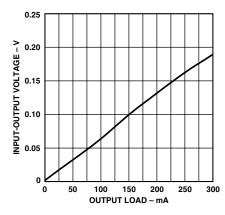
TPC 4. Ground Current vs. Load Current



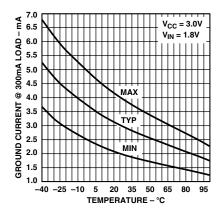
TPC 5. Output Voltage Variation vs. Junction Temperature



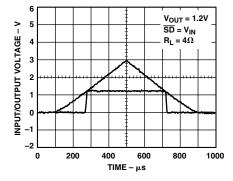
TPC 6. Ground Current vs. Junction Temperature



TPC 7. Dropout Voltage vs. Output Current

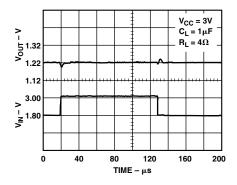


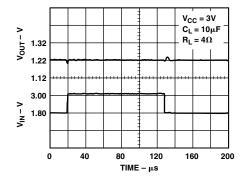
TPC 8. Ground Current @ 300 mA Load vs. Ambient Temperature

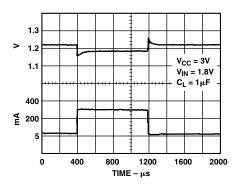


TPC 9. Power-Up/Power-Down

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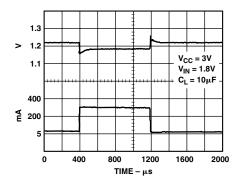


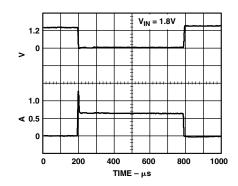


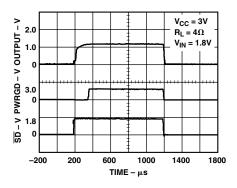
TPC 10. Line Transient Response

TPC 11. Line Transient Response

TPC 12. Load Transient Response



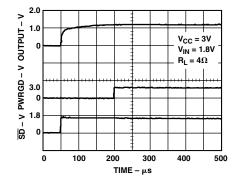


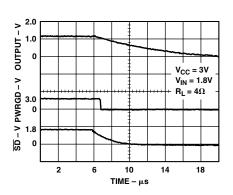


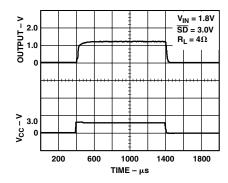
TPC 13. Load Transient Response

TPC 14. Short Circuit Current

TPC 15. Power-On/Power-Off Response from Shutdown





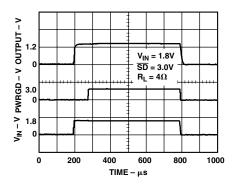


TPC 16. Turn On Delay

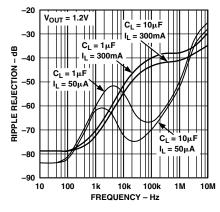
TPC 17. Turn Off Delay

TPC 18. Power On/Power Off Response from  $V_{CC}$ 

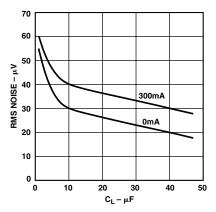
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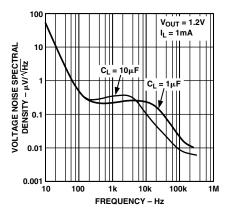
TPC 19. Power On/Power Off Response from  $V_{IN}$ 



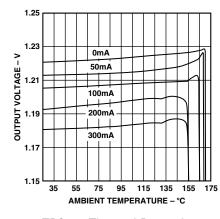
TPC 20. Power Supply Ripple Rejection



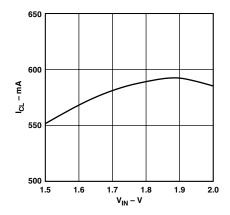
TPC 21. RMS Noise vs.  $C_L$  (10 Hz–100 Hz)



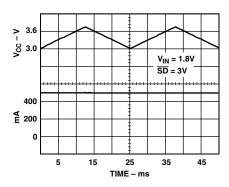
TPC 22. Output Noise Density



TPC 23. Thermal Protection



TPC 24. Current Limit vs. V<sub>IN</sub>



TPC 25. Current Limiting from V<sub>CC</sub>

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#### THEORY OF OPERATION

The new anyCAP LDO ADP3342 uses a single control loop for regulation and reference functions. The output voltage is sensed by a resistive voltage divider consisting of R1 and R2. Feedback is taken from this network by way of a series diode (D1) and a second resistor divider (R3 and R4) to the input of an amplifier.

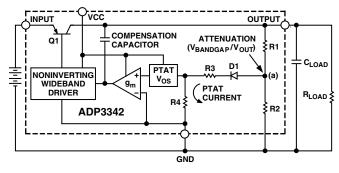


Figure 2. Control Loop Functional Block Diagram

A very high gain error amplifier is used to control this loop. The amplifier is constructed in such a way that at equilibrium it produces a large, temperature proportional input "offset voltage" that is repeatable and very well controlled. The temperature proportional offset voltage is combined with the complementary diode voltage to form a "virtual band gap" voltage, implicit in the network, although it never appears explicitly in the circuit. Ultimately, this patented design makes it possible to control the loop with only one amplifier. This technique also improves the noise characteristics of the amplifier by providing more flexibility on the trade-off of noise sources that lead to a low noise design.

The R1, R2 divider is chosen in the same ratio as the band gap voltage to the output voltage. Although the R1, R2 resistor divider is loaded by the diode D1 and a second divider consisting of R3 and R4, the values can be chosen to produce a temperature stable output. This unique arrangement specifically corrects for the loading of the divider so that the error resulting from base current loading in conventional circuits is avoided.

The patented amplifier controls a new and unique noninverting driver that drives the pass transistor, Q1. The use of this special noninverting driver enables the frequency compensation to include the load capacitor in a pole splitting arrangement to achieve reduced sensitivity to the value, type, and ESR of the load capacitance.

Most LDOs place very strict requirements on the range of ESR values for the output capacitor because they are difficult to stabilize due to the uncertainty of load capacitance and resistance. Moreover, the ESR value, required to keep conventional LDOs stable, changes depending on load and temperature. These ESR limitations make designing with LDOs more difficult because of their unclear specifications and extreme variations over temperature.

With the ADP3342 anyCAP LDO, this is no longer true. It can be used with virtually any good quality capacitor, with no constraint on the minimum ESR. This innovative design allows the circuit to be stable with just a small 1  $\mu F$  capacitor on the output. Additional advantages of the pole splitting scheme include superior line noise rejection and very high regulator gain, which leads to excellent line and load regulation.

Additional features of the circuit include current limit and thermal shutdown and noise reduction.

#### APPLICATION INFORMATION

#### PC Application—VCCVID

The ADP3342 has been optimized for PC applications that require a 1.2 V output for powering the voltage identification rail, VCCVID. The rail from which the output draws current, the IN pin, is separated from the rail that powers the IC, the VCC pin. This allows a higher efficiency design when, as recommended for the IMVP-3 application, the VCC pin is connected to a 3.3 V supply to power the IC adequately, and the IN pin is connected to a 1.8 V supply. The efficiency is nearly 60% in this case.

#### **Capacitor Selection**

As with any voltage regulator, output transient response is a function of the output capacitance. The ADP3342 is stable with a wide range of capacitor values, types, and ESR (anyCAP). A capacitor as low as 1  $\mu F$  is all that is needed for stability; larger capacitors can be used if high output current surges are anticipated. The ADP3342 is stable with extremely low ESR capacitors (ESR  $\approx$  0), such as multilayer ceramic capacitors (MLCC) or OSCON. Note that the effective capacitance of some capacitor types may fall below the minimum at cold temperature. Ensure that the capacitor provides more than 1  $\mu F$  at minimum temperature.

#### **Input Bypass Capacitor**

An input bypass capacitor is not strictly required but is advisable in any application involving long input wires or high source impedance. Connecting a 1  $\mu F$  capacitor from IN to ground reduces the circuit's sensitivity to PC board layout. If a larger value output capacitor is used, then a larger value input capacitor is also recommended.

#### **Power Good Monitoring Function**

The PWRGD pin does not monitor the output voltage directly but rather detects whether the internal PNP pass transistor is being modulated by the regulation loop. This means of detecting PWRGD, rather than using a voltage threshold detection, provides an inherent and desirable delay in asserting the PWRGD signal. During startup or overload, the regulation loop is not in control, so the PWRGD pin is low.

#### Shutdown Mode

Applying a TTL high signal to the shutdown  $(\overline{SD})$  pin, or tying it to the input pin, will turn the output ON. Pulling  $\overline{SD}$  down to 0.4 V or below, or tying it to ground, will turn the output OFF. In shutdown mode, quiescent current is reduced.

#### Paddle-Under-Lead Package

The ADP3342 uses a patented paddle-under-lead package design to ensure the best thermal performance in an MSOP-8 footprint. This new package uses an electrically isolated die attach that allows all pins to contribute to heat conduction. This technique reduces the thermal resistance to 110°C/W on a 4-layer board as compared to >160°C/W for a standard MSOP-8 leadframe.

#### **Thermal Overload Protection**

The ADP3342 is protected against damage due to excessive power dissipation by its thermal overload protection circuit, which limits the die temperature to a maximum of 165°C. Under extreme conditions (i.e., high ambient temperature and power dissipation) where die temperature starts to rise above 165°C, the output current is reduced until the die temperature has dropped

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to a safe level. The output current is restored when the die temperature is reduced.

Current and thermal limit protections are intended to protect the device against accidental overload conditions. For normal operation, device power dissipation should be limited by operating conditions so that junction temperatures will not exceed 150°C.

#### **Calculating Junction Temperature**

Device power dissipation is calculated as follows:

$$P_D = \left(V_{IN} - V_{OUT}\right)I_{LOAD} + \left(V_{IN}\right)I_{GND}$$

Where  $I_{LOAD}$  and  $I_{GND}$  are load current and ground current, and  $V_{IN}$  and  $V_{OUT}$  are input and output voltages, respectively.

Assuming  $I_{LOAD}$  = 300 mA,  $I_{GND}$  = 4 mA,  $V_{IN}$  = 1.8 V, and  $V_{OUT}$  = 1.2 V, device power dissipation is:

$$P_D = (1.8 - 1.2) 300 \text{ } mA + (1.8) 4 \text{ } mA = 187 \text{ } mW$$

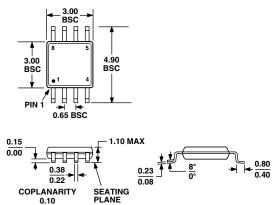
The proprietary package used in the ADP3342 has a thermal resistance of 110°C/W, significantly lower than a standard MSOP-8 package. Assuming a 4-layer board, the junction temperature rise above ambient temperature will be approximately equal to:

$$\Delta T_{JA} = 0.187 W \times 110^{\circ} C/W = 20.6^{\circ} C$$

#### **OUTLINE DIMENSIONS**

#### 8-Lead MSOP Package [MSOP] (RM-8)

Dimensions shown in millimeters



**COMPLIANT TO JEDEC STANDARDS MO-187AA** 

# **Revision History**

Location	Page	<u>;</u>
10/02—Data Sheet changed from REV. 0 to REV. A.		
Changes to PIN CONFIGURATION		
Changes to PIN FUNCTION DESCRIPTION	3	,
OUTLINE DIMENSIONS Updated		8

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